深圳市矽源特科技有限公司 ShenZhen ChipSourceTek Technology Co., Ltd.

2X15W Stereo Class D Audio Amplifier with PL function

HAA3603 General Description

The HAA3603 is an analog input, stereo, high efficiency Class D audio power amplifier. It requires minimal external components and operates a single 8V to 14.4V power supply. The device can driver $2x4\Omega$ speakers and delivering 2X15W peak output power (THD+N=1%) at 12V power supply voltage. When PBTL mode, it can deliver up to 1x30W peak output power into a 2Ω speaker while offering up to 88.5% high efficiency.

The HAA3603 features SSM (spread spectrum modulation), AERC (active edge rate control) and De-phase function to suppress EMI which enables the use of inexpensive ferrite bead filters at the outputs while meeting EMC requirements for system cost reduction.

The HAA3603 features UVP (under-voltage protection), OVP (over-voltage protection), DC speaker protection, OCP (overcurrent protection), OTP (over-temperature protection). All of these protections can be recovered automatically.

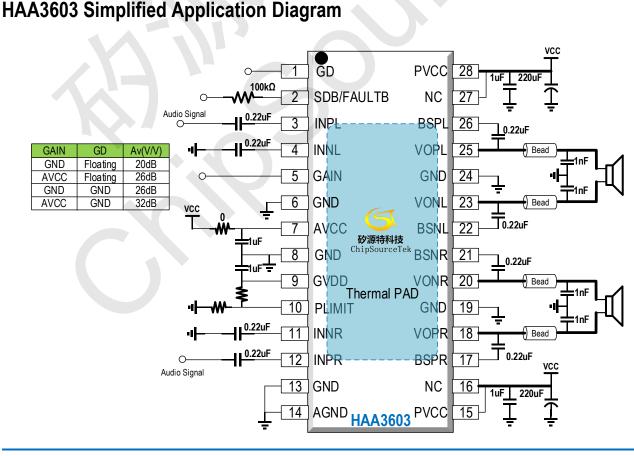
The HAA3603 is available in ETSSOP-28L package.

HAA3603 Features

- ♪ Wide Power Supply: 8V~14.4V
- **J** 2x18.5W Output Power (4Ω @ 12V, THD+N=10%)
- **J** 2x15W Output Power (4Ω @ 12V, THD+N=1%)
- **Δ** 2x10.98W Output Power (6Ω @ 12V, THD+N=1%)
- **\$ 92.5% High Efficiency (10W, 8Ω @ 12V)**
- ♪ 10mA Low Quiescent Supply Current
- ♪ PBTL Output Mode
- ♪ 20dB, 26dB, 32dB Gain Selectable
- ♪ Built-in Power-Limit function
- Built-in SSM, AERC and De-phase function
- ♪ DCP, UVP, OVP, OCP, OTP
- Built-in Pop-and-click noise suppression
- ♪ Available in ETSSOP-28L Package

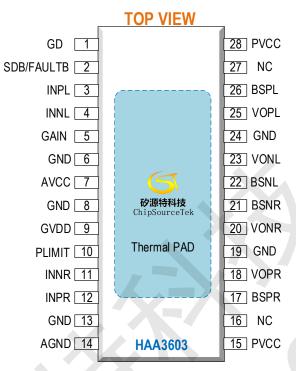
HAA3603 Applications

- Televisions and Monitors
- > BT Speakers & Wireless Speakers
- Sound bars



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HAA3603 Pin Configuration



HAA3603 Pin Functions

No	Name	Туре	Description
1	GD	I	Gain double control pin, connect to GND or floating.
2	SDB/FAULTB	10	Shutdown control pin. Low: shutdown, High: wakeup.
2	3DB/FAULTB	D	Fault reporting when DC speaker protection, OCP, OTP.
3	INPL	- -	Positive audio input for left channel. Connect to GND for PBTL mode
4	INNL	I	Negative audio input for left channel. Connect to GND for PBTL mode
5	GAIN	_	Gain control pin.
6	GND	G	Ground.
7	AVCC	Р	Analog power supply.
8	GND	G	Ground.
9	GVDD	0	Gate driver power supply.
10	PLIMIT	I	Power-limit control. Connect a resistor divider from GVDD to GND to set power limit level.
11	INNR		Positive audio input for right channel.
12	INPR	-	Negative audio input for right channel
13	GND	G	Ground.
14	AGND	G	Ground.
15,16	PVCC	Р	Power supply for right channel.
17	BSPR	0	Bootstrap supply for right channel, positive high-side power nLDMOS.
18	VOPR	0	Positive audio output for right channel.
19	GND	G	Power ground for right channel.
20	VONR	0	Negative audio output for right channel.
21	BSNR	0	Bootstrap supply for right channel, negative high-side power nLDMOS.
22	BSNL	0	Bootstrap supply for left channel, negative high-side power nLDMOS.
23	VONL	0	Negative audio output for left channel.



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24	GND	G	Power ground for left channel.	
25	VOPL	0	sitive audio output for left channel.	
26	BSPL	0	otstrap supply for left channel, positive high-side power nLDMOS.	
27,28	PVCC	Р	Power supply for left channel.	
	Thermal PAD		Connect to GND for best thermal and electrical performance.	

HAA3603 Operating Control Description

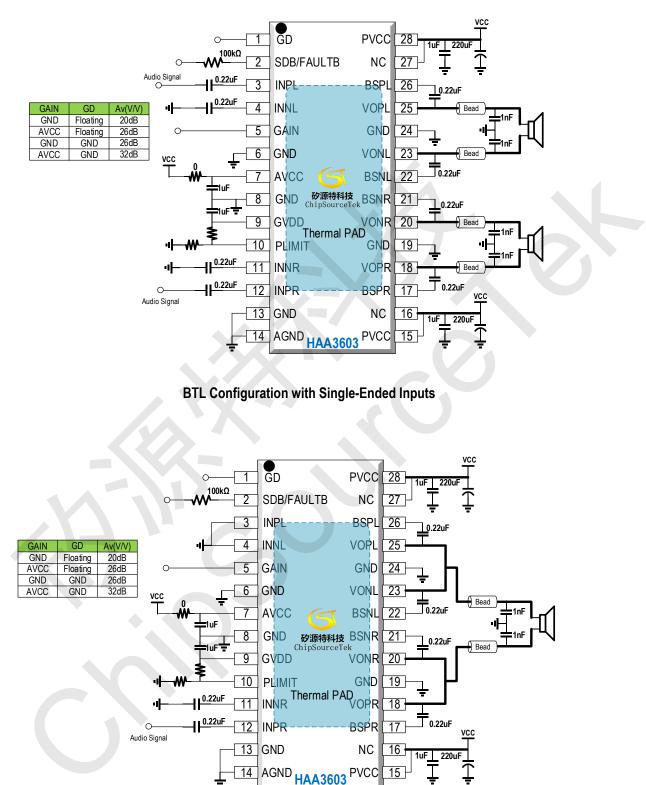
PIN Name	Connection Method	Mode Description
SDB/FAULTB	High	Startup
SUD/FAULID	Low	Shutdown
	GAIN = GND, GD = Floating	Gain = 20dB
GAIN	GAIN = AVCC/Floating, GD = Floating	Gain = 26dB
GD	GAIN = GND, GD = GND	Gain = 26dB
	GAIN = AVCC/Floating, GD = GND	Gain = 32dB
INPL, INNL	Both to GND	PBTL Mode

HAA3603 Order Information

Part No.	Package	Mark	Tape and Reel Information
HAA3603	ETSSOP-28L	G HAA3603 XXXXX	2500pcs/Reel

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HAA3603 Typical Application Circuits



PBTL Configuration with Single-Ended Inputs



HAA3603 Absolute Maximum Ratings

Over operating free-air temperature range, TA= 25°C (unless otherwise noted)(1)

	Parameter	Min	Max	Unit
Supply Voltage	AVCC, PVCC	-0.3	18	V
	SDB/FAULTB, GAIN	-0.3	AVCC+0.3	V
Input Voltage	INL, IPL, INR, IPR	-0.3	5.5	V
	PLIMIT, GD	-0.3	GVDD+0.3	V
Operating free-air tempe	erature range T _A	-40	85	°C
Operating junction temp	erature range TJ	-40	150	°C
Storage temperature rar	nge T _{STG}	-40	125	°C
ESD Ratings		V Z I		
Human Body Model (HE	SM) ESD ⁽²⁾	±2	000	V
Charged Device Model	(CDM) ESD ⁽²⁾	±5	500	V
Thermal Metric				
θ _{JA} Junction-to-ambie	nt thermal resistance	30.3		°C /W
θ _{JC(top)} Junction-to-cas	e (top) thermal resistance	33	3.5	°C /W

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) This device series contains ESD protection and passes the following tests:

Human Body Model (HBM) standard: ESDA/JEDEC JS-001-2017 for all pins.

Charged Device Model (CDM) standard: ANSI/ESDA/JEDEC JS-002-2018 for all pins.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

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HAA3603 Electrical Characteristics

AVCC=PVCC=12V, T_A = 25°C, R_L = 4Ω +33µH, Cin = 0.22μ F (unless otherwise noted)

	Parameter		Condition	n & Desci	iption	Min	Тур	Max	Unit
Vcc	Supply voltage		PV	CC, AVCC)	8		14.4	V
GVDD	Gate drive supply		SD/FAULT=GND, IGVDD=2mA			4.8	5	5.2	V
lsd	SD current						10		μA
lq	Quiescent current						9.5		mA
UVP	Under voltage protection						7.5		V
OTP	Over temperature protection						155		°C
Ton	Turn on time						48.8		ms
Toff	Turn off time				VZ		12.8		us
Input PIN	1)								
VIH	High logic input					2		AVCC	V
VIL	Low logic input		SDB/F/	AULTB, G	AIN,	0		0.65	V
V _{OL}	Low logic output	SDE	B/FAULTB, [•]	100kΩ pu	ll-up resistor			0.6	V
Class D		•							
Vos	Output offset Voltage		Gain=2	26dB, CP	<=2	-10	0	10	mV
ſ	OSC frequency						330		kHz
fськ	SSM frequency Range					-10.5		10.5	%
				014	THD+N=1%		3.75		-
			2 x 8Ω	8V	THD+N=10%		4.62		
					THD+N=1%		8.3		
				12V	THD+N=10%		10.3		
			BTL 2 x 6Ω		THD+N=1%		4.89		
					8V	THD+N=10%		6.05	
		BIL		1011	THD+N=1%		10.98		
				12V	THD+N=10%		13.56		-
					THD+N=1%		6.9		
- 0			2 x 4Ω 12V	8V	THD+N=10%		8.5		
Po ⁽²⁾	Output power	Output power		THD+N=1%		15.2		W	
				12V	THD+N=10%		18.5		
					THD+N=1%		7.55		
				8V THD+N=	THD+N=10%		9.3		1
			4Ω	1011	THD+N=1%		16.8		
	PBTL	DOT		12V	THD+N=10%		20.8		
		PBTL			THD+N=1%		13.5		-
				8V	THD+N=10%		16.6		
		2Ω		THD+N=1%		29.6		1	
				12V	THD+N=10%		36.6		
			2 x 8Ω		Po = 10W		92.5		
		BTL	2 x 6Ω		Po = 11W		91.5		1
ŋ	Efficiency		2 x 4Ω	12V	Po = 15W		88		%
		PBTL	4Ω		Po = 20W		93.1		

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			2Ω		Po = 30W		88.5			
Ron	On resistance of Power MOS	0.5A, High Side				150				
RUII	On resistance of Power MOS		0.5A	, Low Side	e		150		mΩ	
t _{dcdet}	DC detect time						800		ms	
Vn	noise		A-weighti	ng, Gain=	20dB		75		u)/rma	
VII	noise		A-weighting, Gain=26dB			95		μVrms		
	Crosstalk	٧	/o=1Vrms, C	Gain=26dE	3, f=1kHz		-100		dB	
SNR	Signal-to-noise ratio		Output power at THD+N=1%			101		dB		
PSRR		200r	nVpp ripple	at 1kHz,	Gain=26dB		-70		dB	
THD+N	Total harmonic distortion + noise		f=1k	Hz,Po=5V	V		0.04		%	
	Iotal harmonic distortion + hoise		f=1k⊦	lz,Po=12\	N		0.05		%	
			GAIN = GN	ID, GD = I	Floating	19	20	21		
Coin		GAI	N = AVCC/F	loating, G	D = Floating	25	26	27		
Gain	Audio Gain		GAIN = G	ND, GD =	GND	25	26	27	dB	
		GA	IN = AVCC/	Floating,	GD = GND	31	32	33		

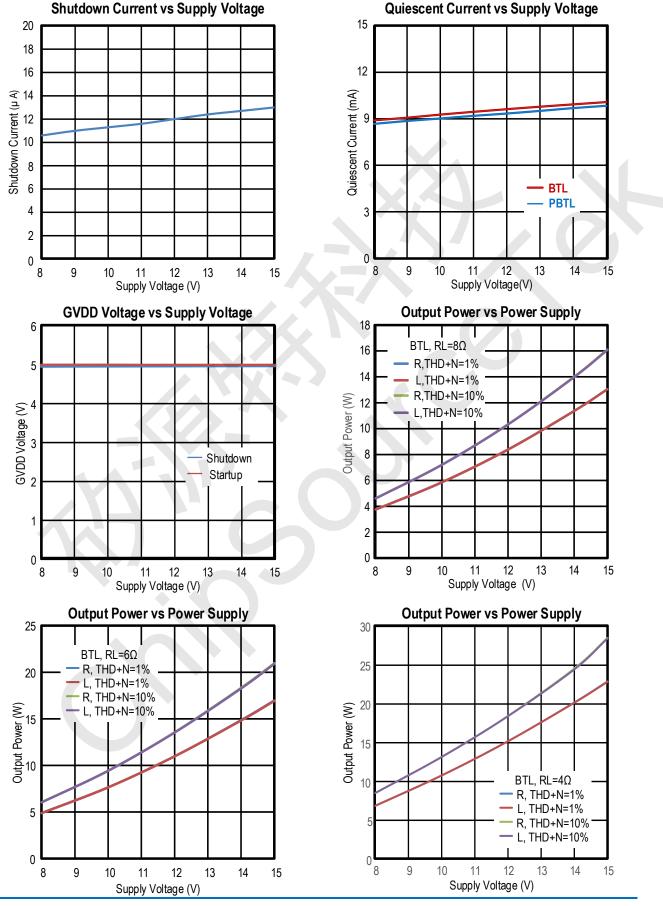
(1): Set SDB/FAULTB to high level, make sure the pull-up resistor is larger than $4.7k\Omega$ and smaller than $500k\Omega$.

(2): High output power of HAA3603 needs good thermal dissipation. It will be thermal protection if the heat dissipation is not good

enough. If necessary, a heat sink can be used for thermal dissipation.

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HAA3603 Typical Characteristics



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10

0

0

0

0

20 2k 4k 6k

5

10

BTL

Gain = 26dB

8

9

Output Power vs Power Supply

10 11 12 Supply Voltage (V)

Efficiency vs Output Power

20

Output Power (W)

Noise vs Frequency

Frequency (Hz)

8k 10k 12k 14k 16k 18k

25 30

15

13

PBTL

PVCC =12V

35 40

4Ω

2Ω

45

AP

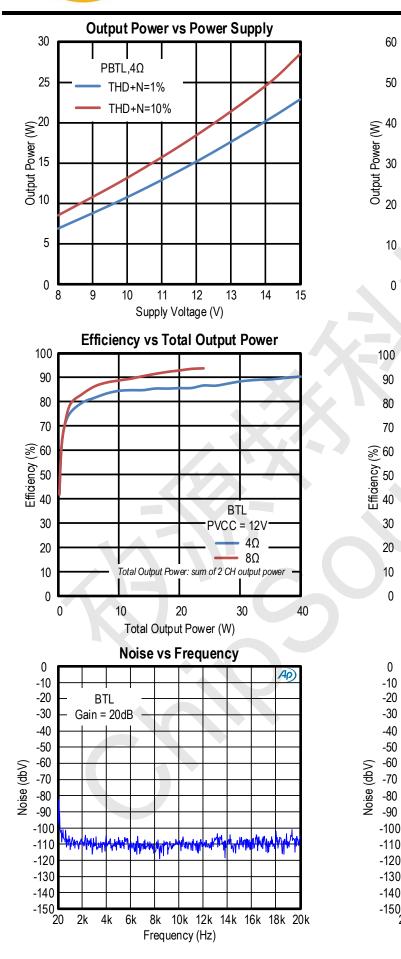
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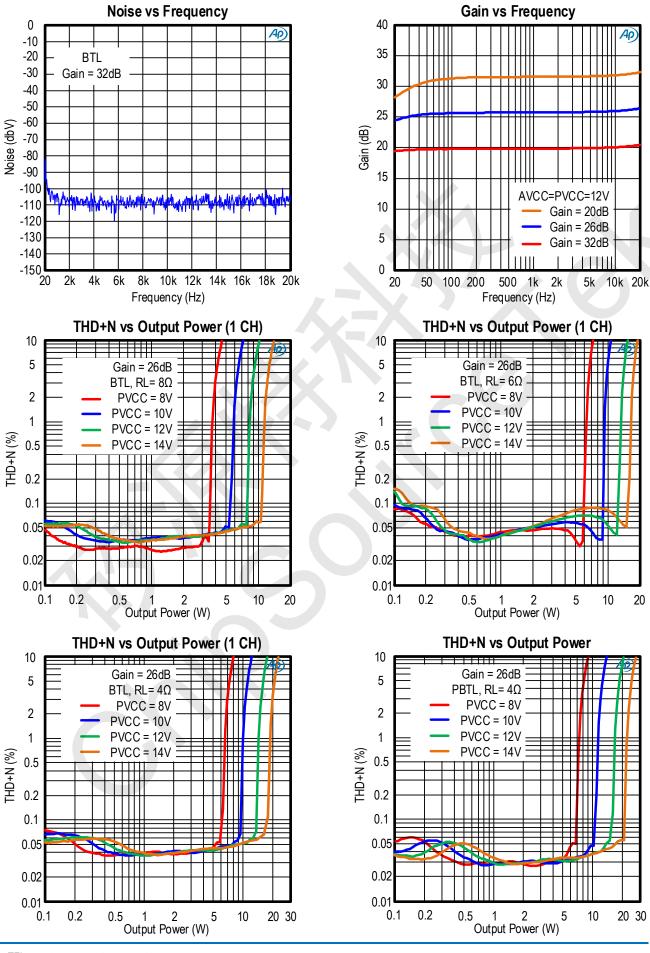
PBTL,2Ω

THD+N=1%

THD+N=10%

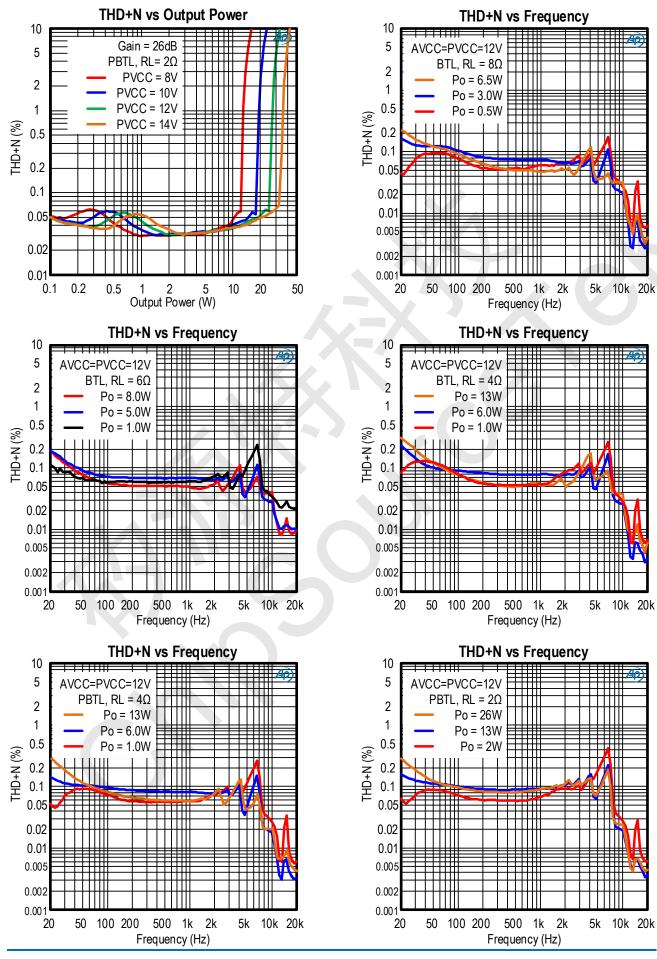


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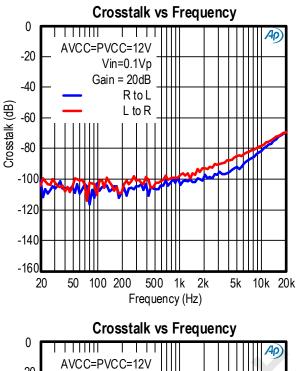
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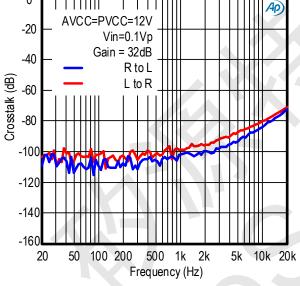
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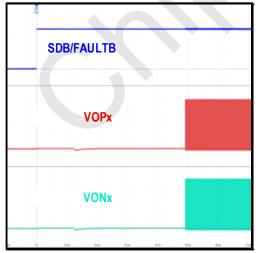
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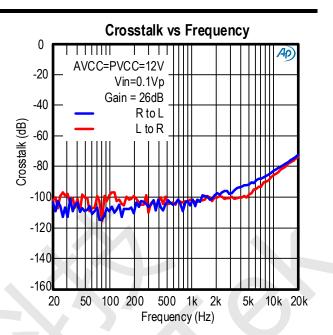
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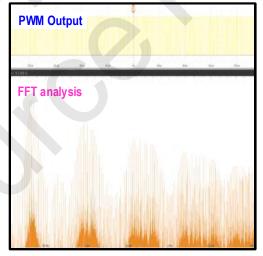


Startup Sequence Diagram

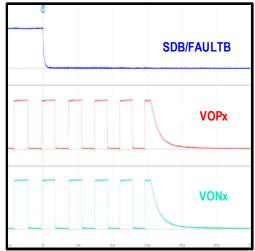




FFT Diagram of SSM Output



Shutdown Sequence Diagram





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HAA3603 Functional Description

The HAA3603 stereo Class-D audio amplifier features a filter-less modulation scheme that greatly reduces the external component count, conserving board space and reducing system cost. The HAA3603 does not require an output filter; it relies on the inherent inductance of the speaker coil and the natural filtering of the speaker and human ear to recover the audio component of the square wave output.

Differential Inputs

The HAA3603 features a differential input structure, making them compatible with many CODECs, and offering improved noise immunity over a single-ended input amplifier. In devices such as flat-panel displays, noisy digital signals can be picked up by the amplifier's inputs. These signals appear at the amplifier's inputs as common-mode noise. A differential input amplifier amplifies only the difference of the two inputs, while any signal common to both inputs is attenuated.

The HAA3603 can also be configured as a single-ended input application by AC capacity coupling either input to GND and driving the other input. It is recommended to put the ac ground input parallel with the signal input and connect to GND near the audio source which for better noise immunity.

For good transient performance, the impedance seen at each of the two differential inputs should be the same. The impedance seen at the inputs should be limited to an RC time constant of 3ms or less if possible. This is to allow the input dc blocking capacitors to become completely charged during the 49-ms power-up time. If the input capacitors are not allowed to completely charge, there is some additional sensitivity to component matching which can result in pop if the input components are not well matched.

Gain Selection

GAIN PIN	GD PIN	Gain (dB)
GND	Floating	20
AVDD/Floating	Floating	26
GND	GND	26
AVDD/Floating	GND	32

The HAA3603 has 3 gain settings which can be selected by setting GAIN and GD pins. See Table Below.

Internal Analog Supply (GVDD)

The HAA3603 includes an integrated low dropout (LDO) linear regulator to generate a 5 V supply which used to power the gates of the output full bridge transistors. This analog supply voltage is available at the GVDD pin. Connect a 1 μ F decoupling capacitor from this pin to the GND pin. The GVDD pin is not recommended to be used as a voltage source for external circuitry.

Diagnostic SDB/FAULTB Operation

The HAA3603 features a shutdown mode that reduces power consumption. Driving SDB/FAULTB pin low places the device in low-power (10 μ A) shutdown mode. When device is in shutdown mode, the output of amplifier becomes weak low (a state grounded through approximately 10k Ω resistance). Connect SDB/FAULTB high for normal operation. Never leave SDB/FAULTB unconnected, because the amplifier operation would be unpredictable. For the best power-off pop performance, place the amplifier in the shutdown mode prior to removing the power supply voltage.

The SDB/FAULTB pin is also an output pin which reports protection state. When OCP, OTP, DCP is triggered, the SDB/FAULTB is activated to low level. An internal circuit will pull down it to enter shutdown mode. The pin can be connected to power supply by a high pull-up resistor to reduce the maximum sinking current of the pin.



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POP-AND-CLICK SUPPRESSION

Voltage transients at the outputs of the audio amplifiers may occur when shutdown is activated or deactivated. Voltage transients as small as 10 mV can be heard as an audible pop in the speaker. Clicks and pops are defined as undesirable audible transients generated by the amplifier system that do not come from the system input signal. Such transients may be generated when the amplifier system changes its operating mode. For example, system power-up and power-down can be sources of audible transients.

The HAA3603 features comprehensive click-and-pop suppression that eliminates audible transients on startup and shutdown. While in shutdown, the H-bridge is pulled to GND through internal resistor. During startup or power-up, the input amplifiers are muted and an internal loop sets the modulator bias voltages to the correct levels, preventing clicks and pops when the H-bridge is subsequently enabled. Additionally, well matched input capacitors and small input RC time constant can reduce this noise.

BD Modulation

HAA3603 features PWM output signal with a carrier frequency of approximately 330 kHz, which built-in 2nd integrating loop filter to improve the THD+N performance. Each output is switching from 0 volts to the supply voltage with 50% duty cycle at quiescent state. The VOPx and VONx are in phase with each other with no input so that there is little or no current in the speaker. The duty cycle of VOPx is greater than 50% and VONx is less than 50% for positive output voltages. The duty cycle of VOPx is greater than 50% for negative output voltages. The voltage across the load sits at 0 V throughout most of the switching period, reducing the switching current, which reduces any I²R losses in the load.

	Quiescent
	VOP
	VON
	VOP-VONIL 0A
	Positive Output
	VOP
	VON
<	

PBTL Selection (Mono Mode)

The HAA3603 features a PBTL mode that allows the right and left channels to operate in parallel, achieving up to 30W of output power with a 2Ω speaker - a particularly useful feature for driving the subwoofer in a 2.1 audio system. The PBTL mode is enabled by connecting INPL and INNL pins to GND and applying the input signal to INPR and INNR. In this mode, the positive and negative outputs of each channel (left and right) are synchronized and in phase. Speaker will be placed between the Left and Right outputs with VOPL connected to VONL and VOPR connected to VONR to parallel the output half bridges for highest power efficiency.

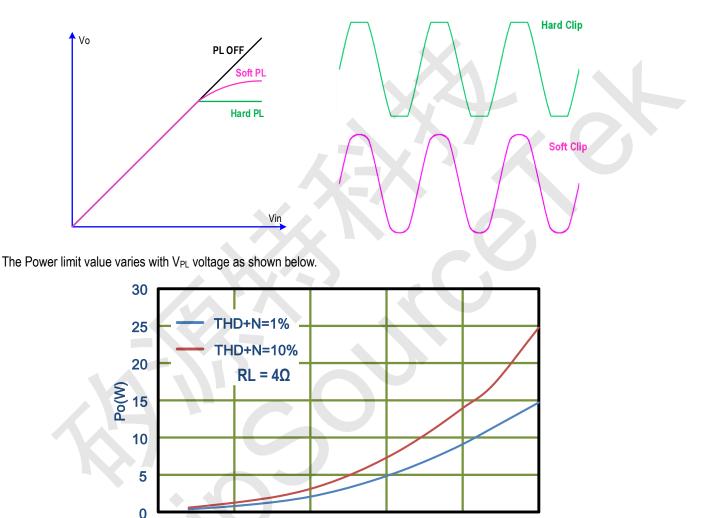
When the device is placed in PBTL mode on a PCB with outputs wired together, ensure that the INPL and INNL pins can never be driven high. Driving the INPR and INNR pins high while the outputs are wired together in PBTL mode may trigger the OCP or OTP or both, and may even damage the device.



PL (Power Limit) Function

A built-in power limit is used to limit the output voltage level below the supply rail by limiting the duty cycle. Using this function protects small speakers which used in high voltage power supply, as the maximum output power can be limited. The limit level is set through the voltage (V_{PL})) at PLIMIT pin. The pin voltage is set by voltage dividing resistors from GVDD to GND. The setting values shown here are common to BTL and PBTL mode.

HAA3603 features soft clip power limit to reduce the harmonic distortion which has better sound quality than hard clip.



1.5

V_{PL}(V)

2

2.5

Low EMI Noise

The HAA3603 uses a proprietary modulation and several functions to minimize EMI during playing audio. The HAA3603 can pass FCC Class-B emissions testing with unshielded 20 inch cable only using ferrite bead-based filtering.

1

0.5

SSM (Spread-Spectrum)

The HAA3603 features a spread-spectrum (SSM) function that flattens the wideband spectral components, improving EMI emissions that may be radiated by the speaker and cables. In SSM function, the switching frequency varies by $\pm 10.5\%$ around the center frequency. The period of the triangle waveform changes from cycle to cycle. Instead of a large amount of spectral energy present at multiples of the switching frequency, the energy is now spread over a bandwidth that increases with frequency. Above a few megahertz, the wideband spectrum looks like white noise for EMI purposes.

0



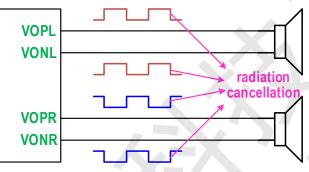
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AERC (Active Edge Rate Control)

The switch edge of amplifier output brings obvious EMI radiation. And the faster the edge rate, the more serious the radiation. A slower edge rate can reduce EMI radiation, but with a consequent reduction in efficiency. HAA3603 applies AERC function to the output stage, which only reduces the internal driving capacity when the edge changes. Therefore, the EMI radiation is reduced while the efficiency loss is reduced.

De-phase

The HAA3603 features de-phase function which inverts the phase of the output PWM such that the idle output PWM waveforms of the two audio channels are inverted. De-phase does not affect the audio signal, or its polarity.



Protection functions

The HAA3603 is fully protected against UVP (under-voltage protection), OVP (over-voltage protection), OTP (over-temperature protection), OCP (over-current protection) and DCP (DC detection protection) as explained below. The behavior of the device under the different fault conditions differs according to the protection activated and is described in the following sections.

UVP

This is the function to protect the device when the supply voltage is unusually lowered. If the supply voltage drops below the UVP threshold voltage, the protection is activated which forces the outputs to the high-impedance state. When the supply voltage recovers the device restarts.

OVP

This is the function to protect the device when the supply voltage is unusually raised. If the supply voltage exceeds the OVP threshold voltage, the protection is activated which forces the outputs to the high-impedance state. When the supply voltage recovers the device restarts.

OTP

This is the function to prevent damage to the device when the internal die temperature exceeds the threshold temperature. If the OTP is activated, the chip is disabled until the temperature drops below the recovery threshold. This hysteresis prevents rapid cycling of the output at high temperatures. Once the die temperature exceeds the thermal triggering point, the device is switched to the shutdown state and the outputs are disabled. Thermal protection faults are reported on the SDB/FAULTB pin.

OCP

This is the function to protect the device by detecting short-circuiting conditions. If the output current exceeds the threshold value, the overcurrent protection is activated, the device is switched to the shutdown state and the outputs are disabled. The device will recover automatically when the fault is removed. Over-current protection faults are reported on the SDB/FAULTB pin.



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DCP

This is the function to protect the speaker connected to the amplifier output when a DC signal is continuously output. The DC current which might occur due to defective capacitors on the input or shorts on the printed circuit board at the inputs. A DC detect fault will be reported on the SDB/FAULTB pin as a low state and switch the device to shutdown state. The device will recover automatically when the fault is removed.

A DC Detect Fault is issued when the output differential duty-cycle of either channel exceeds approximately22% (for example, +61%, -39%) for more than 800ms at the same polarity. This feature protects the speaker from large DC currents or AC currents less than 2 Hz. To avoid nuisance faults due to the DC detect circuit, hold the SDB/FAULTB pin low at power-up until the signals at the inputs are stable. Also, take care to match the impedance seen at the positive and negative inputs to avoid nuisance DC detect faults.



HAA3603 Application Information

The HAA3603 features SSM, AERC, De-phase functions to remove the inductor filter in applications like as TV sets, sound docks and Bluetooth speakers. Depending on output power requirements and necessity for load protection, the built in PL function can be used to control system power, see functional description of this feature.

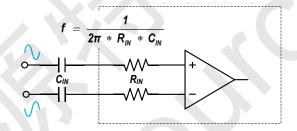
Special attention should be paid to the power-stage power supply; this includes component selection, PCB placement, and routing. For optimal electrical performance, EMI compliance, and system reliability, it is important that each PVCC pin is decoupled with ceramic capacitors placed as close as possible to each supply pin. It is recommended to follow the PCB layout Description below.

Input Filter (Input Capacitor Selection)

The input impedance is set by an internal resistor which is selected by gain setting. As shown below.

Gain (dB)	Rin_int (kΩ)
20	40
26	20
32	10

An input capacitors are required if the input signal is not biased within the recommended input dc common-mode voltage range. If high-pass filtering is needed at the input, the input capacitor and the input resistor of the HAA3603 form a high-pass filter with a corner frequency determined by the following figure.



For Gain=26dB and C_{IN} =0.22µF, the high pass cutoff frequency is about 36Hz. A further consideration for this capacitor is the leakage path from the input source through the input network and the feedback network to the load. This leakage current creates a dc offset voltage at the input to the amplifier that reduces useful headroom, especially in high gain applications. For this reason, a low-leakage tantalum or ceramic capacitor is the best choice. Additionally, lead-free solder can create dc offset voltages and it is important to ensure that boards are cleaned properly.

The input capacitor should be match well and can significantly affect the performance of the circuit. Failure to use input capacitors degrades the output offset of the amplifier.

Bootstrap Capacitors

The output stage of the HAA3603 uses a high-side NMOS driver, rather than PMOS driver. To generate the gate drive voltage for the high-side NMOS driver, a bootstrap capacitor for each output terminal acts as a floating power supply for the switching cycle. Using 0.22 µF ceramic capacitors with a voltage rating of 25 V or greater is recommended.

For a properly functioning bootstrap circuit, the ceramic capacitor must be closed to each bootstrap pin and the power-stage output pin. When the power-stage output is low, the bootstrap capacitor is charged through an internal diode connected between the gate-drive power-supply pin (GVDD) and the bootstrap pins. When the power-stage output is high, the bootstrap capacitor potential is shifted above the output potential and thus provides a suitable voltage supply for the high-side gate driver. These capacitors ensure sufficient energy storage, even during clipped low frequency audio signals, to keep the high-side power stage FET (nLDMOS) fully turned on during the remaining part of its ON cycle.



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Power Supply Decoupling

To ensure high efficiency, low total harmonic distortion, and high power supply rejection ratio, proper power supply decoupling is necessary. Noise transients on the power supply lines are short-duration voltage spikes. These spikes can contain frequency components that extend into the hundreds of megahertz. Decouple the power supply input with a good quality aluminum electrolytic capacitors larger than 220 µF that are placed on the power supply of each channel. This capacitor bypasses low frequency noises to the ground plane which serves as a local storage capacitor for supplying current during large signal transients from the speaker. For high frequency transient noises, good quality low ESR and ESL ceramic capacitors typical 1µF and 1nF should be placed as close as possible to the power supply of each channel. A 1µF ceramic capacitor should be placed on the AVCC pin and a small resistor between AVCC and PVCC can be used to keep high frequency noise from entering the analog circuit. 25V capacitor rating is recommended.

Output Filter

The HAA3603 does not require an output filter. However, output filtering can be used if a design is failing radiated emissions due to board layout or cable length, or the circuit is near EMI-sensitive devices. The tuning and component selection of the filter should be optimized for the load.

Ferrite Bead Filter

Several emissions suppression technology are used in HAA3603 eliminates the need for expensive LC filter. Low-cost ferrite bead-based filters can meet the requirements. In this case it is necessary to carefully select the ferrite bead used in the filter.

One important aspect of the ferrite bead selection is the type of material used in the ferrite bead. Not all ferrite material is alike, so it is important to select a material that is effective in the 10 to 100 MHz range which is key to the operation of the Class-D amplifier. Many of the specifications regulating consumer electronics have emissions limits as low as 30 MHz. It is important to use the ferrite bead filter to block radiation in the 30 MHz and above range from appearing on the speaker wires and the power supply lines which are good antennas for these signals. The impedance of the ferrite bead can be used along with a small capacitor with a value in the range of 1nF to reduce the frequency spectrum of the signal to an acceptable level. For best performance, the resonant frequency of the ferrite bead/ capacitor filter should be less than 10 MHz.

Also, it is important that the ferrite bead is large enough to maintain its impedance at the peak currents expected for the amplifier. Some ferrite bead manufacturers specify the bead impedance at a variety of current levels. In this case it is possible to make sure the ferrite bead maintains an adequate amount of impedance at the peak current the amplifier will see. If these specifications are not available, it is also possible to estimate the bead's current handling capability by measuring the resonant frequency of the filter output at low power and at maximum power. A change of resonant frequency of less than 50% under this condition is desirable.

A high quality ceramic capacitor is also needed for the ferrite bead filter. A low ESR capacitor with good temperature and voltage characteristics will work best.

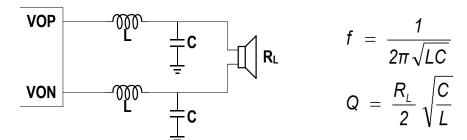
Additional EMC improvements may be obtained by adding snubber networks from each class D outputs to ground. Suggested values for a simple RC series snubber network would be 10 Ω in series with a 330-pF capacitor although design of the snubber network is specific to every application and must be designed taking into account the parasitic reactance of the printed circuit board as well as the audio amp. Take care to evaluate the stress on the component in the snubber network especially if the amp is running at high PVCC. Also, make sure the layout of the snubber network is tight and returns directly to the GND or the thermal pad beneath the chip.

LC Filter

There may be a few circuit instances where it is necessary to add a complete LC reconstruction filter. These circumstances might occur if there are nearby circuits which are sensitive to noise. In these cases a classic second order Butterworth filter should be

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used shown below. The recommended component values are listed in the table below. Using these constants makes a cut-off frequency from 20 kHz~50 kHz with Q \approx 0.7.



L (µH)	C (µF)	f (kHz)	Q
33	1	27.7	0.7
22	0.68	41.2	0.7
22	1	33.9	0.64
15	1	41.1	0.77
10	0.68	61	0.78
15	2.2	27.7	0.77
10	1	50	0.63
10	0.68	61	0.52
	33 22 22 15 10 15 10	33 1 22 0.68 22 1 15 1 10 0.68 15 2.2 10 1	33 1 27.7 22 0.68 41.2 22 1 33.9 15 1 41.1 10 0.68 61 15 2.2 27.7 10 1 50



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PCB Layout Considerations

As output power increases, it must take care to layout PCB traces and wires properly among the amplifier, load, and power supply; a poor layout increases voltage drops, consequently decreasing efficiency. A good practice is to use short, wide PCB tracks to decrease voltage drops and minimize inductance.

Proper grounding guidelines help to improve audio performance, minimize crosstalk between channels, and prevent switching noise from coupling into the audio signal. Analog ground and power ground should be connected at the thermal pad, which should be used as a central ground connection or star ground.

To maintain high output swing and high peak output power, ensure that the PCB traces that connect the output pins to the load and supply pins are as wide as possible to maintain the minimum trace resistances. It is also recommended that a large ground plane be used for minimum impedances. Keep the current loop from each of the outputs through the ferrite bead and the small filter cap and back to GND as small and tight as possible. The size of this current loop determines its effectiveness as an antenna. In addition, good PCB layout isolates critical analog paths from sources of high interference. High frequency circuits (analog and digital) should be separated from low frequency circuits.

The ferrite-bead filter or LC filter should be placed as close to the output pins as possible for the best EMI performance. The capacitors used in both the ferrite-bead and LC filters should be grounded to power ground. In addition, properly designed multilayer PCBs can reduce EMI emission and increase immunity to the RF field by a factor of 10 or more compared with double-sided boards. A multilayer board allows a complete layer to be used for the ground plane, whereas the ground plane side of a double-sided board is often disrupted by signal crossover.

If the system has separate ground planes for small signal and high power connections, there should be no overlap between these planes. Stitch the power plane to the exposed Thermal pad using multiple vias. Proper layout improves heat conduction into the board, allowing operation at larger output power levels without over-temperature issues.

PCB Material Recommendation

FR-4 Glass Epoxy material with 1 oz. (35 µm) is recommended. The use of this material can provide for higher power output, improved thermal performance, and better EMI margin (due to lower PCB trace inductance). It is recommended to use several GND underneath the device thermal pad for thermal coupling to a bottom side copper GND plane for best thermal performance.

Thermal Considerations

Class D amplifiers provide much better efficiency and thermal performance than a comparable Class AB amplifier. However, the system's thermal performance must be considered with realistic expectations along with its many parameters.

• Crest factor (Continuous Sine Wave vs. Music)

Crest factor is the ratio of the instantaneous peak amplitude of a waveform, to its root mean square RMS value. Typically music has a crest factor of 10 to 20dB and the sine wave is 3dB. When a Class D amplifier is evaluated in the lab, often a continuous sine wave is used as the signal source. While this is convenient for measurement purposes, it represents a worst-case scenario for thermal loading on the amplifier. It is not uncommon for a Class D amplifier to enter thermal shutdown if driven near maximum output power with a continuous sine wave. The PCB must be optimized for best dissipation.

Audio content, both music and voice, has a much lower RMS value relative to its peak output power. Therefore, while an audio signal may reach similar peaks as a continuous sine wave, the actual thermal impact on the Class D amplifier is highly reduced. If the thermal performance of a system is being evaluated, it is important to use actual audio signals instead of sine waves for testing. If sine waves must be used, the thermal performance is less than the system's actual capability for real music or voice.

• PCB Thermal Considerations

The exposed pad is the primary route for conducting heat away from the IC. With a bottom-side exposed pad, the PCB and its



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copper becomes the primary heat-sink. Solder the exposed pad to a copper polygon. Add as much copper as possible from this polygon to any adjacent pin on the Class D amplifier as well as to any adjacent components, provided these connections are at the same potential. These copper paths must be as wide as possible. Each of these paths contributes to the overall thermal capabilities of the system.

The copper polygon to which the exposed pad is attached should have multiple hot solid vias to the opposite side of the PCB, where they connect to another copper polygon. Make this polygon as large as possible within the system's constraints for signal routing. Additional improvements are possible if all the traces from the device are made as wide as possible. Although the IC pins are not the primary thermal path out of the package.

• Heat-sink requirements

If operating in higher ambient temperatures, it is possible to improve the thermal performance of a PCB with the addition of an external heat-sink. The thermal resistance to this heat-sink must be kept as low as possible to maximize its performance. With a bottom-side exposed pad, the lowest resistance thermal path is on the bottom of the PCB. Placing heat-sink on the back of the PCB which under the device will bring obvious effects. But it will bring some structural problem in the design. Sometime, attaching heat-sink to the topside of the device with thermal conductive silicone is more appropriate.

• Thermal Calculations

The die temperature of a Class D amplifier can be estimated with some basic calculations. For example, the die temperature is calculated for the below conditions:

 T_A = +35°C, P_{OUT} = 2x10W, η = 92.5%, θ_{JA} = 30.3°C/W

Then, the Class D amplifier's power dissipation can be calculated:

$$P_{DISS} = \frac{P_{OUT}}{\eta} - P_{OUT} = 1.622W$$

Then the die temperature can be calculated:

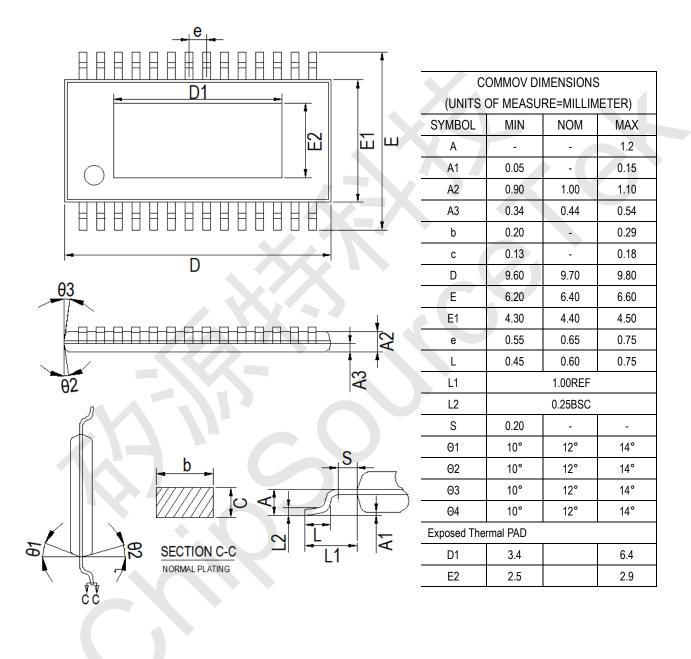
$$T_C = T_A + P_{DISS} * \theta_{JA} = 84.15^{\circ}\text{C}$$

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HAA3603 Package Outline

ETSSOP-28L

Plastic thermal enhanced thin shrink small outline package, 28 leads. Body width 4.4 mm, body length 9.7mm, lead pitch 0.65 mm, exposed die pad.





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Revision History

	No	Date	Description
F	V0.1	20220508	Preliminary version
ſ	V1.0	20220606	First release

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